NSN 5962-01-236-6687

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View Online at https://aerobasegroup.com/nsn/5962-01-236-6687

Body Length: 0.785 inches Body Width:	
0.302 inches	
Body Height:	
0.175 inches	
Maximum Power Dissipation Rating:	
332.8 milliwatts	
Dperating Tempurature Range:	
55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
65.0/+150.0 degrees celsius	
eatures Provided:	
fermetically sealed and burn in and bipolar and programmable and w/enable	
nclosure Material:	
Ceramic	
nclosure Configuration:	
Dual-in-line	
Dutput Logic Form:	
ransistor-transistor logic	
nput Circuit Pattern:	
input	
erminal Surface Treatment:	
older	
oltage Rating And Type Per Characteristic:	
7.0 volts power source	
Time Rating Per Chacteristic:	
0.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time	e, high to low level
utput	
lemory Device Type:	
Rom	
Memory Capacity:	
Jnknown	
Fest Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).	
Ferminal Type And Quantity:	
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Νο	

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